



### 100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
100V	$8.5 \text{m}\Omega$ @ $V_{GS} = 10V$	46A
1007	13.6mΩ @ V <sub>GS</sub> = 4.5V	36A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Synchronous rectifiers
- Backlighting
- Power management functions
- DC-DC converters

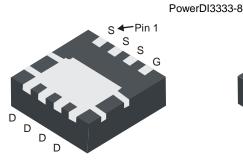
### **Features and Benefits**

- Low Rds(ON) Ensures On-State Losses are Minimized
- Excellent Q<sub>gd</sub> x R<sub>DS(ON)</sub> Product (FOM)
- Advanced Technology for DC/DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMTH10H009LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

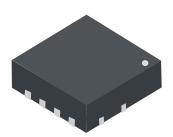
https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

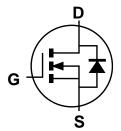
- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 63
- Weight: 0.034 grams (Approximate)







Top View



**Equivalent Circuit** 

### Ordering Information (Note 4)

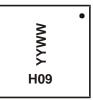
Part Number	Package	Packing		
Part Number	Fackage	Qty.	Carrier	
DMTH10H009LFGQ-7	PowerDI3333-8	2,000	Tape & Reel	
DMTH10H009LFGQ-13	PowerDI3333-8	3,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



H09 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	100	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Ocationary Durin Ocamer (Alexa 5) V 40V	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	lo	12 8	А
Continuous Drain Current (Note 5) Vgs = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lo	46 32	А
Maximum Continuous Body Diode Forward Current (N	ls	30	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ірм	184	Α	
Pulsed Body Diode Continuous Current (10µs Pulse,	I <sub>SM</sub>	184	Α	
Avalanche Current (L = 1mH)	las	17	Α	
Avalanche Energy (L = 1mH)		Eas	144.5	mJ

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5) T <sub>A</sub> = +25°C		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0</sub> JA	60	°C/W	
Total Power Dissipation $T_C = +25^{\circ}C$		PD	39	W
Thermal Resistance, Junction to Case		Rелс	3.8	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	VGS = 0V, ID = 1mA	
Zero Gate Voltage Drain Current	IDSS			1	μA	V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss			±100	nA	V <sub>G</sub> S = ±20V, V <sub>D</sub> S = 0V	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	Vgs(th)	1.1	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D-s/s/	_	6.4	8.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	8.2	13.6	11177	$V_{GS} = 4.5V, I_D = 10A$	
Diode Forward Voltage	VsD		0.8	1.2	V	VGS = 0V, IS = 20A	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	2361	_		V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss		611	_	рF		
Reverse Transfer Capacitance	Crss		16	_			
Gate Resistance	Rg	_	1.7	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	41	_	V 50V L 40A		
Gate-Source Charge	Qgs	_	7.3	_	nC	V <sub>DD</sub> = 50V, I <sub>D</sub> = 13A V <sub>GS</sub> = 10V	
Gate-Drain Charge	Qgd	_	9.3	_		VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	7	_		$V_{DD} = 50V, V_{GS} = 10V$ $I_{D} = 13A, R_{g} = 6\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	12	_	no		
Turn-Off Delay Time	tD(OFF)	_	42	_	ns		
Turn-Off Fall Time	tF	_	24	_			
Reverse Recovery Time	t <sub>RR</sub>	_	45	_	ns	1- 424 dl/dt 4004/vo	
Reverse Recovery Charge	Qrr	_	68	_	nC	I <sub>F</sub> = 13A, dl/dt = 100A/μs	

Notes:

<sup>6.</sup> Short duration pulse test used to minimize self-heating effect. 7. Guaranteed by design. Not subject to product testing.

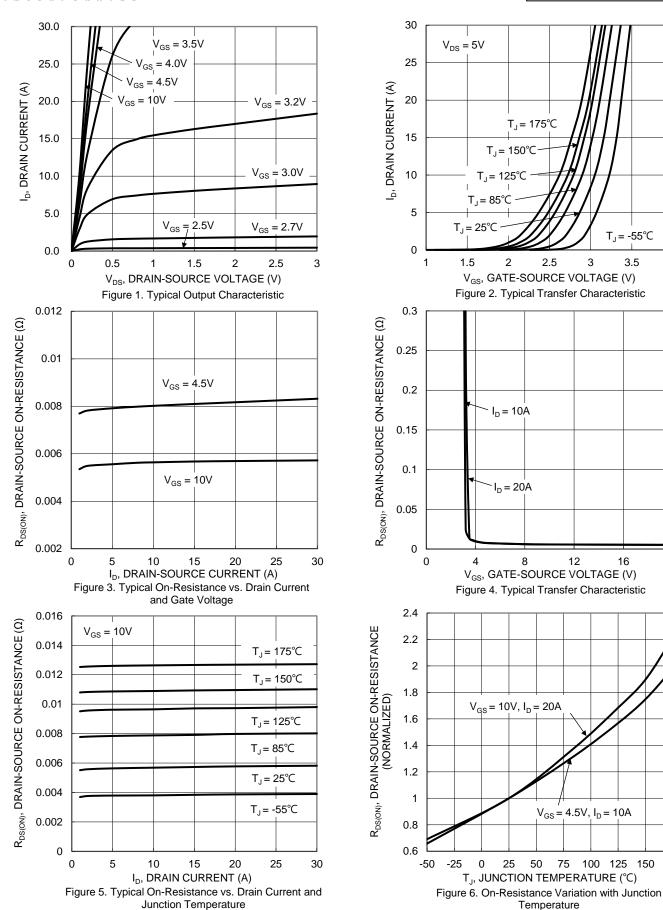


3.5

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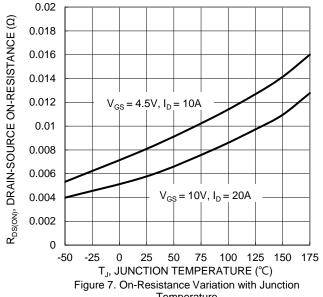
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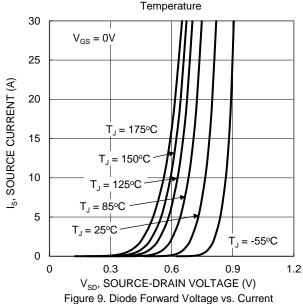












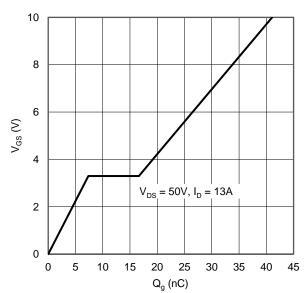


Figure 11. Gate Charge

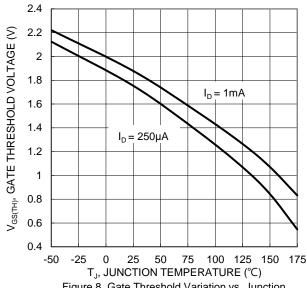
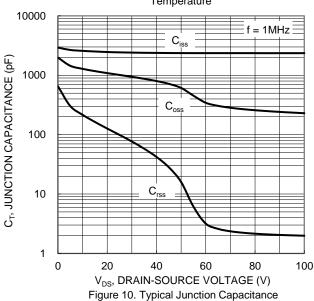


Figure 8. Gate Threshold Variation vs. Junction Temperature



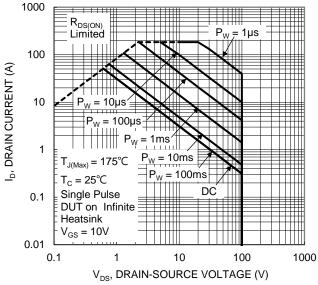


Figure 12. SOA, Safe Operation Area

January 2023

DMTH10H009LFGQ



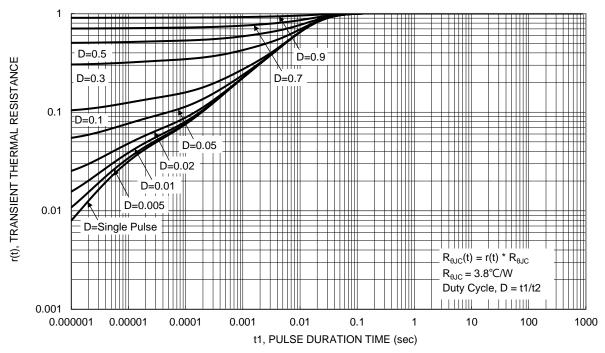


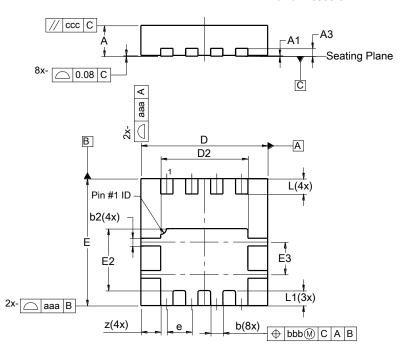
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8

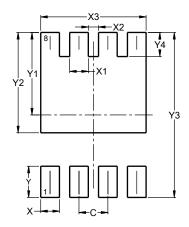


PowerDI3333-8				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05	0.02	
<b>A</b> 3	1	1	0.203	
b	0.27	0.37	0.32	
b2	_	_	0.20	
D	3.25	3.35	3.30	
D2	2.22	2.32	2.27	
E	3.25	3.35	3.30	
E2	1.56	1.66	1.61	
E3	0.79	0.89	0.84	
е	-	-	0.65	
L	0.35	0.45	0.40	
L1	1	1	0.39	
Z	_	_	0.515	
aaa	0.25			
bbb	0.10			
CCC	0.10			
All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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